

**ZXTP01500BG** 

#### 500V PNP HIGH PERFORMANCE TRANSISTOR IN SOT223

### **Features**

- BV<sub>CEO</sub> > -500V
- I<sub>C</sub> = -150mA High Continuous Current
- I<sub>CM</sub> = -500mA Peak Pulse Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>ZXTP01500BGQ</u>)

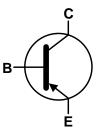
### **Mechanical Data**

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208<sup>(3)</sup>
- Weight: 0.112 grams (Approximate)

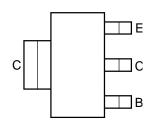




Top View



Device Symbol



Top View Pin-Out

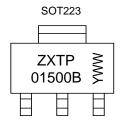
#### **Ordering Information** (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP01500BGTA	AEC-Q101	ZXTP 01500B	13	12	1,000
ZXTP01500BGTC	AEC-Q101	ZXTP 01500B	13	12	4,000

#### Notes

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



ZXTP01500B = Product Type Marking Code YWW = Date Code Marking Y or  $\overline{Y}$  = Last Digit of Year (ex: 7 = 2017) WW or  $\overline{WW}$  = Week Code (01 to 53)



# **Absolute Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-500	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-500	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I <sub>CM</sub>	-500	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	В	2	W
Power Dissipation	(Note 6)	$P_{D}$	3	W
Thormal Posistance, Junction to Ambient	(Note 5)	<b>D</b>	62.5	°C/W
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R <sub>0</sub> JL	14.8	°C/W
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

# ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

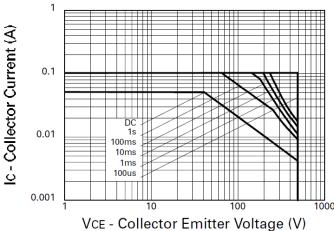
Notes:

- 5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in steady-state.
- 6. Same as note (5), except the device is mounted on 50mm x 50mm 2oz copper.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

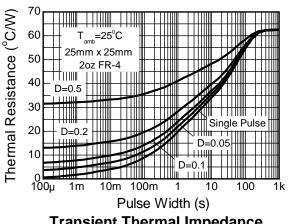
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



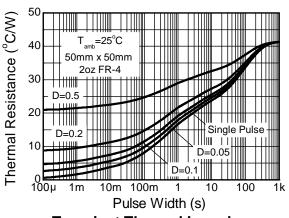
### **Thermal Characteristics and Derating Information**



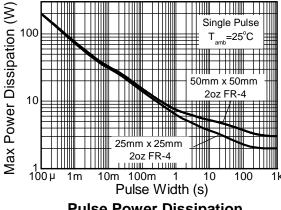
Safe Operating Area



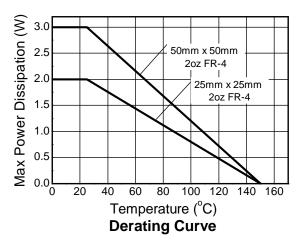
**Transient Thermal Impedance** 



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July 2017



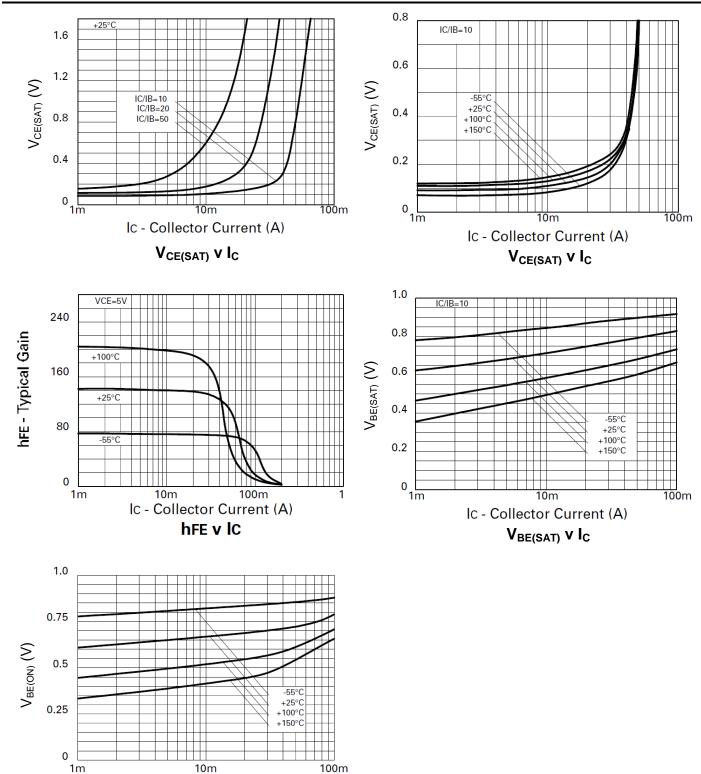
### Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-500	_	_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-500	_	_	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	_	_	V	$I_E = -100 \mu A$
Collector Cut-off Current	I <sub>CBO</sub>	_	_	-100	nA	V <sub>CB</sub> = -500V
Collector Cut-off Current	I <sub>CES</sub>	_	_	-100	nA	V <sub>CE</sub> = -500V
Emitter Cut-off Current	I <sub>EBO</sub>	_	_	-100	nA	V <sub>EB</sub> = -5.6V
Collector Emitter Seturation Valtage (Note 0)		_	_	-200	mV	$I_C = -20 \text{mA}, I_B = -2 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)	VCE(SAT)	E(SAT) —	_	-500		$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Saturation Voltage (Note 9)	V <sub>BE(SAT)</sub>	_	_	-900	mV	$I_C = -50 \text{mA}, I_B = -10 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	V <sub>BE(ON)</sub>	_	_	-900	mV	$I_C = -50 \text{mA}, V_{CE} = -10 \text{V}$
		100	_	300		$I_{C} = -1 \text{mA}, V_{CE} = -10 \text{V}$
DC Current Gain (Note 9)	h <sub>FE</sub>	80	_	300	_	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V
		_	15	_		I <sub>C</sub> = -100mA, V <sub>CE</sub> = -10V
Current Gain-Bandwidth Product	f⊤	60	_	_	MHz	$V_{CE} = -20V, I_{C} = -10mA$ f = 50MHz
Turn-On Time	t <sub>ON</sub>	_	110	_	ns	V <sub>CC</sub> = -100V, I <sub>C</sub> = -50mA
Turn-Off Time	t <sub>OFF</sub>	_	1.5	_	μs	$I_{B1} = -5mA$ , $I_{B2} = 10mA$
Output Capacitance	Сово	_	_	8	pF	V <sub>CB</sub> = -20V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



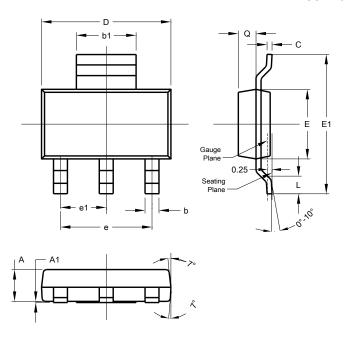
Ic - Collector Current (A)



# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT223**

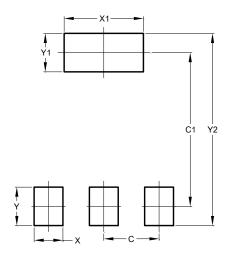


SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
C	0.20	0.30	0.25		
D	6.45	6.55	6.50		
Е	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
е	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
Ø	0.84	0.94	0.89		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT223**



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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